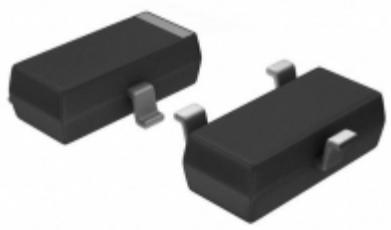





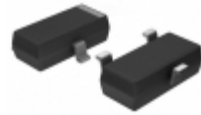


	<h2 style="color: red;">FJV3104RMTF</h2> <p>Hersteller-Teilenummer: FJV3104RMTF</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: TRANS PREBIAS NPN 200MW SOT23-3</p> <p>Datenblätter: 1.FJV3104RMTF.pdf 2.FJV3104RMTF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 476770 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FJV3104RMTF
Hersteller	Fairchild/ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	476770 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	68 @ 5mA, 5V
Frequenz - Übergang	250MHz
Widerstand - Base (R1) (Ohm)	47k
Widerstand - Emitter-Basis (R2) (Ohm)	47k
Verpackung	Original-Reel®

FJV3104RMTF ist neu im Original, Suche FJV3104RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3104RMTF Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3104RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV3102RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 0.2W SOT23-3</p>	 <p>FJV3103RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3106RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3102RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 0.2W SOT23-3</p>
 <p>FJV3106RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3105RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3103RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3107RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>

heiße Teile

Mehr

⚙ FJV1845EMTF	➔ FJV1845EMTF	➔ FJV1845FMTF	D FJV1845FMTF	➔ FJV1845PMTF
⊣ FJV1845PMTF	⚙ FJV1845UMTF	D FJV1845UMTF	➔ FJV3101RLIMTF	➔ FJV3101RMTF
⚙ FJV3101RMTF	⊣ FJV3102RMTF	⚙ FJV3102RMTF	➔ FJV3103RMTF	➔ FJV3103RMTF
D FJV3104RMTF	⚙ FJV3105RMTF	⊣ FJV3105RMTF	⚙ FJV3106RMTF	➔ FJV3106RMTF
➔ FJV3107RMTF	➔ FJV3107RMTF	⚙ FJV3108RMTF	⊣ FJV3108RMTF	➔ FJV3109R
➔ FJV3109RMTF	➔ FJV3109RMTF	D FJV3110RMTF	⚙ FJV3110RMTF	⊣ FJV3111RMTF
⚙ FJV3111RMTF	D FJV3112RMTF	➔ FJV3112RMTF	➔ FJV3113RMTF	➔ FJV3113RMTF
⊣ FJV3114RMTF	⚙ FJV3114RMTF	➔ FJV3115RMTF	➔ FJV3115RMTF	➔ FJV4101RMTF
⚙ FJV4101RMTF	⊣ FJV4102RLIMTF	⚙ FJV4102RMTF	D FJV4102RMTF	➔ FJV4103RMTF
➔ FJV4103RMTF	⚙ FJV4104RMTF	⊣ FJV4104RMTF	⚙ FJV4105RMTF	➔ FJV4105RMTF

Contact us: Info@Y-IC.com

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